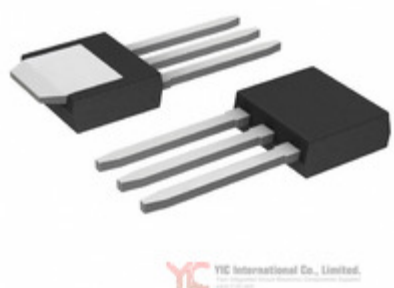

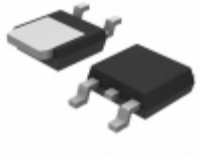
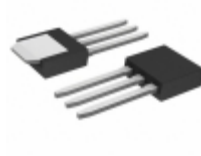
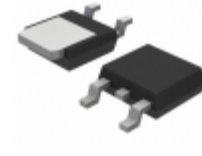


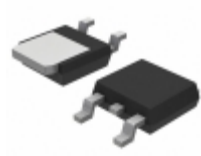
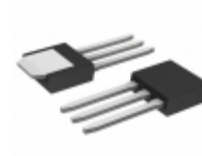
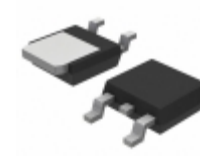
	<p>NTD32N06-1G</p>
	<p>Hersteller-Teilenummer: NTD32N06-1G</p>
	<p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p>
	<p>Teil der Beschreibung: MOSFET N-CH 60V 32A IPAK</p>
	<p>Datenblätter:  NTD32N06-1G.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 5000 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD32N06-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 32A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.5W (Ta), 93.75W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Ta)
Rds On (Max) @ Id, Vgs	26 mOhm @ 16A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1725pF @ 25V
Verpackung	Tube











NTD32N06-1G ist neu im Original, Suche NTD32N06-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD32N06-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD32N06-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD32N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06L-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD32N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD30N06RT4 O NTD30N06RT4 O</p>
 <p>NTD30N02T4G ON NTD30N02T4G ON</p>	 <p>NTD32N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06L-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD32N06G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>

heiße Teile

Mehr

- | | | | | |
|--|--|---|---|---|
|  NTD3055-150G |  NTD3055-150T4 |  NTD3055-150T4G |  NTD3055-170T4G |  NTD30555L104T4G |
|  NTD3055L |  NTD3055L04T4G |  NTD3055L104 |  NTD3055L104-1G |  NTD3055L104G |
|  NTD3055L104T4G |  NTD3055L170 |  NTD3055L170-001 |  NTD3055L170-1G |  NTD3055L170G |
|  NTD3055L170T4 |  NTD3055L170T4G |  NTD3055LT4G |  NTD3055VLT4G |  NTD30N02G |
|  NTD30N02T4 |  NTD30N02T4G |  NTD30N06RT4 |  NTD30N06T4G |  NTD32N06-001 |
|  NTD32N06G |  NTD32N06L |  NTD32N06L-001 |  NTD32N06L-1G |  NTD32N06LG |
|  NTD32N06LT4G |  NTD32N06T4G |  NTD3808NT4G |  NTD3813NT4G |  NTD3817NT4G |
|  NTD40N03R |  NTD40N03R-1 |  NTD40N03R-1G |  NTD40N03RG |  NTD40N03RT4 |
|  NTD40N03RT4G |  NTD4302-001 |  NTD4302-001G |  NTD4302-1G |  NTD4302G |
|  NTD4302T4 |  NTD4302T4G |  NTD4804N |  NTD4804NT4G |  NTD4805N |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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